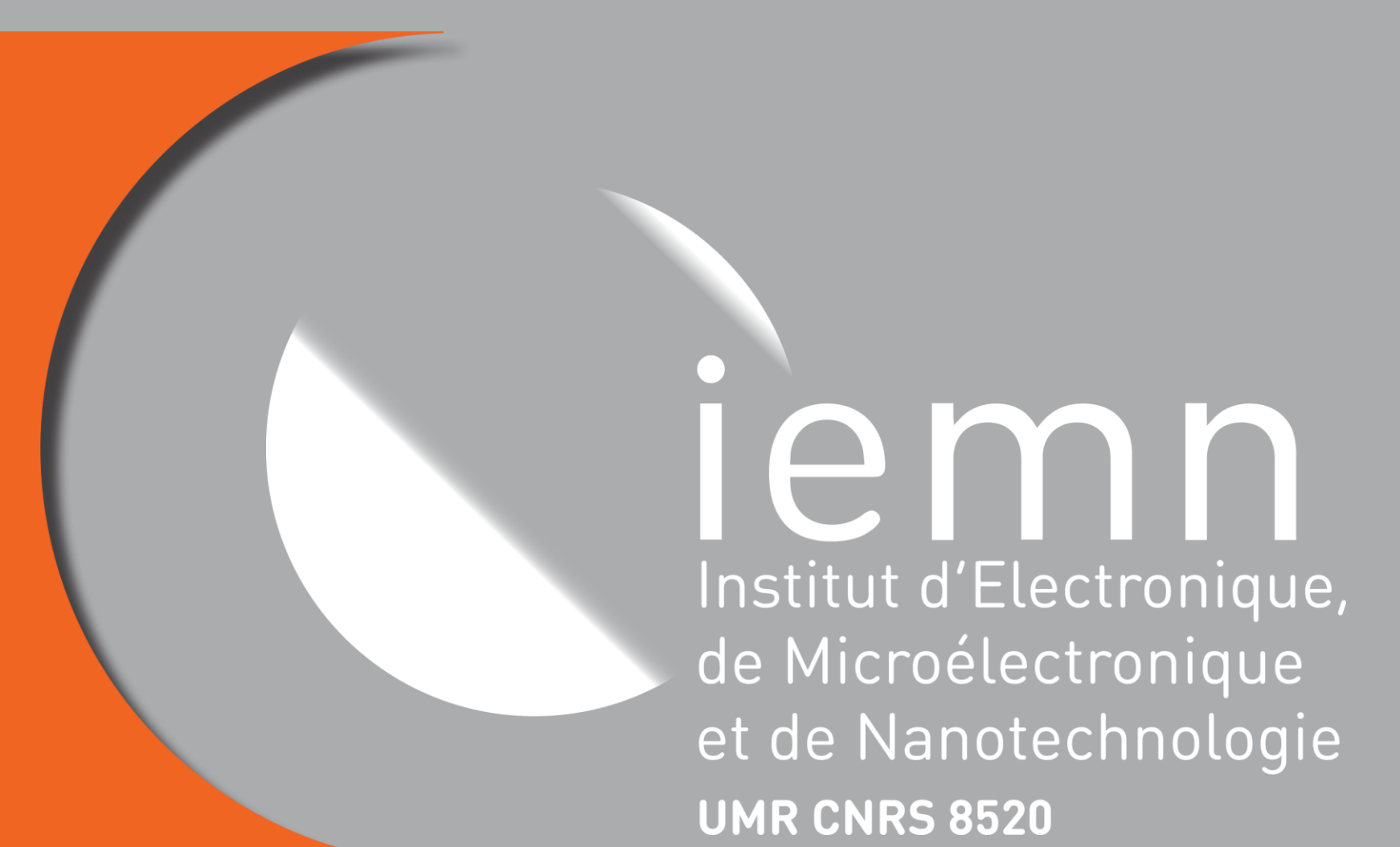


# EPIPHY GROUP

## Epitaxy and Physics of Heterostructures



Permanent researchers : Djamila Hourlier (DR CNRS), Ludovic Desplanque (MCF), Dominique Vignaud (CR CNRS) and Xavier Wallart (DR CNRS)

Engineer: C.Coinon

Post-doc: Walter Batista Pessoa

PhD Students: Wijden Khelifi, Jawad Hadid

### Main thematic

#### Elaboration and characterization of (nano)materials for high frequency, low power applications and advanced devices:

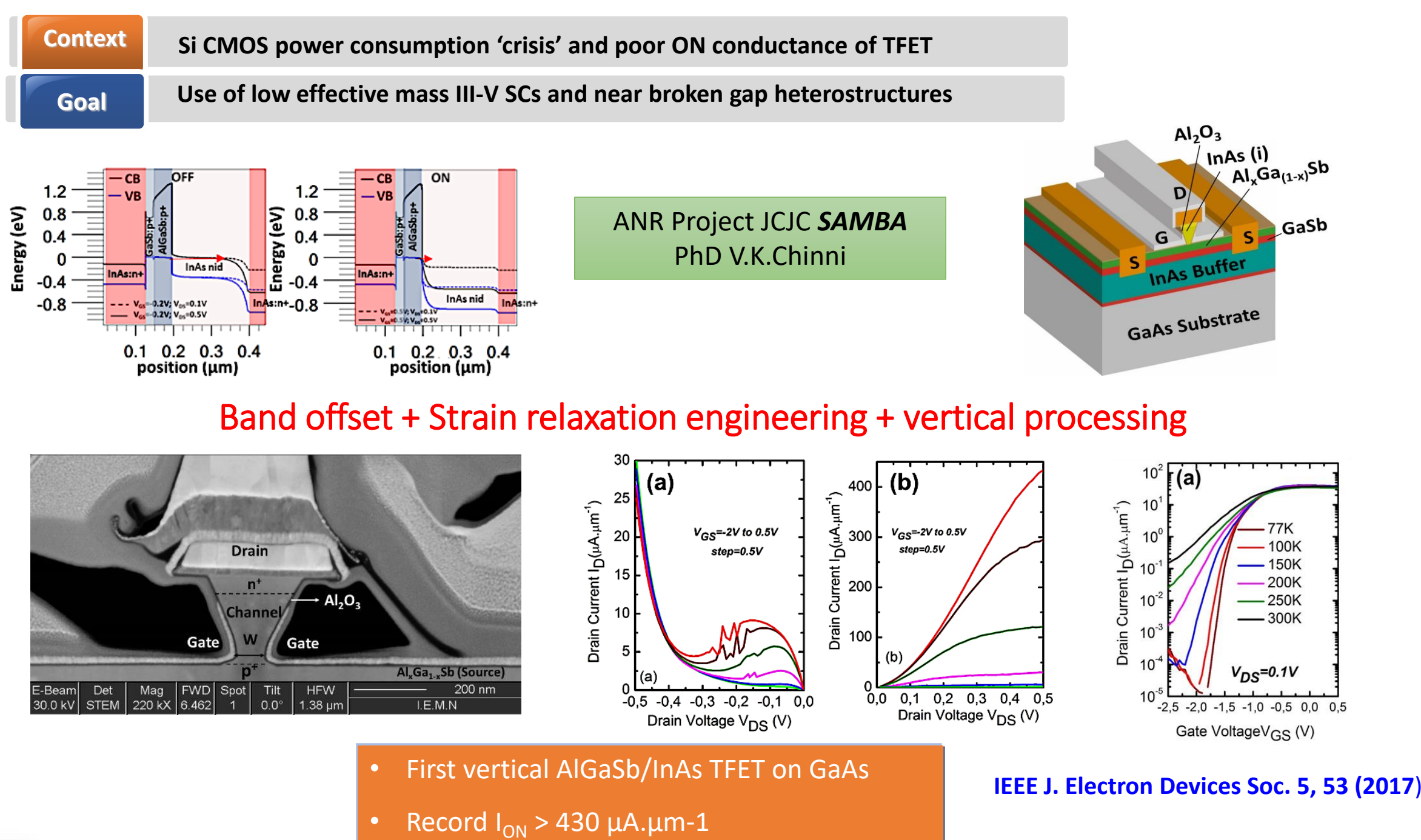
- III- V semiconductors : 2D heterostructures and nanostructures
- 2D materials : graphene epitaxy on SiC and metals – hBN epitaxy - Transition Metal Dichalcogenides (TMDC)
- Organic-inorganic composite nanomaterials

### General objectives

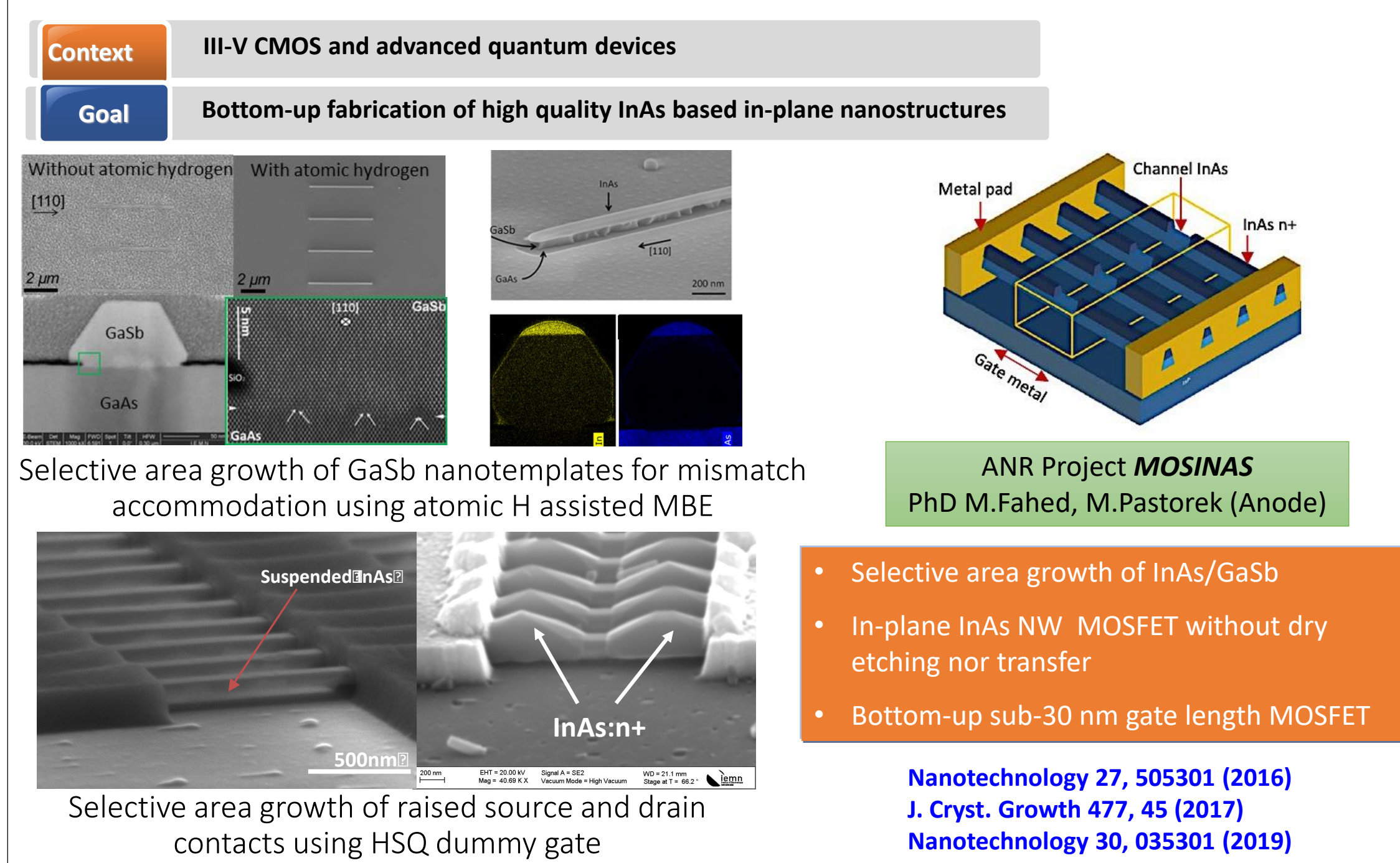
- Growth of controlled structures for device purposes
- Understanding growth mechanisms
- Development of new processes or material heterostructures for advanced devices
- In-depth physical and chemical characterization of grown materials

## III-V semiconductor epitaxy for advanced electronic devices

### Epitaxy of InAs/AlGaSb heterostructures for Tunnel FET (Coll. Anode Group)

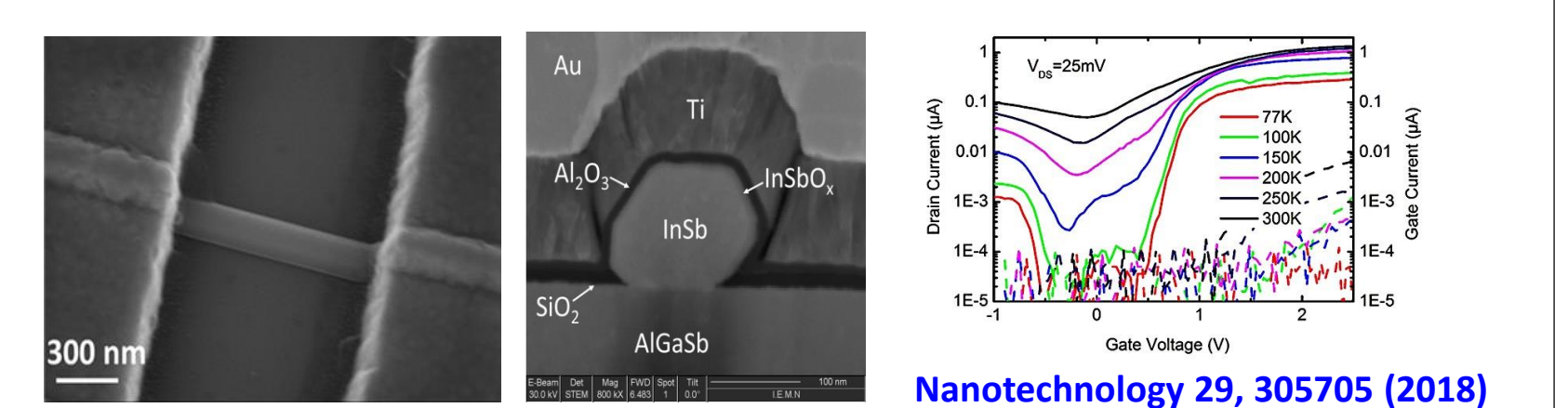


### Selective area Molecular Beam Epitaxy for InAs Nanowire MOSFET (coll. Anode Group, C2N)



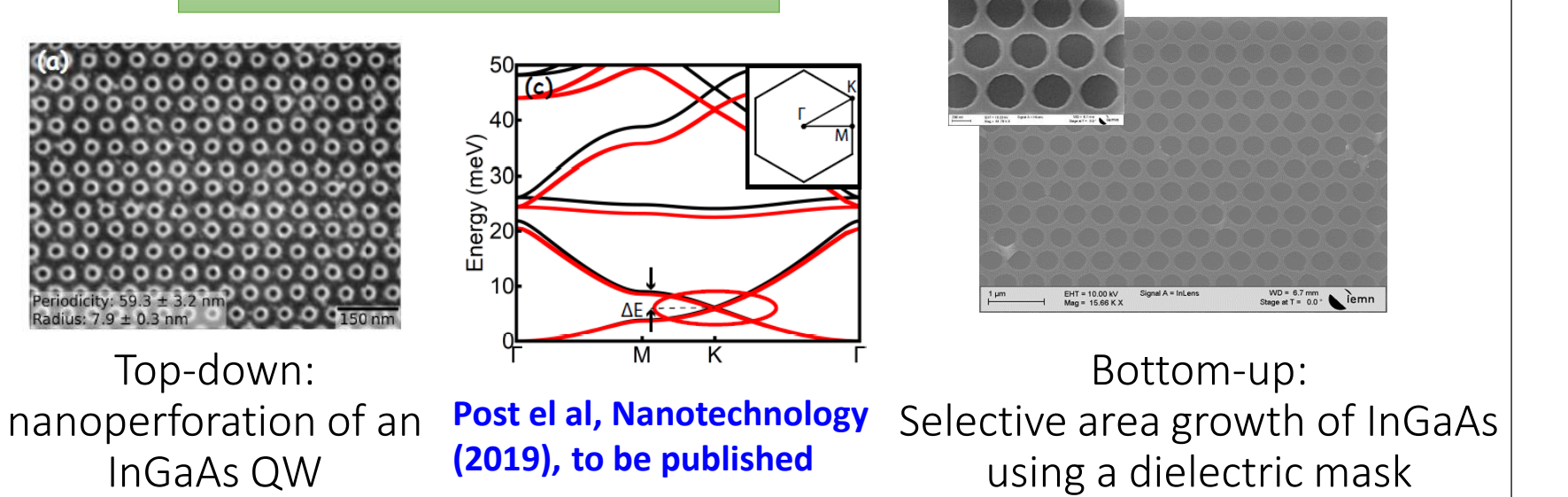
### On-going studies and outlook...

Selective Growth and characterization of in-plane InSb NW for spin devices



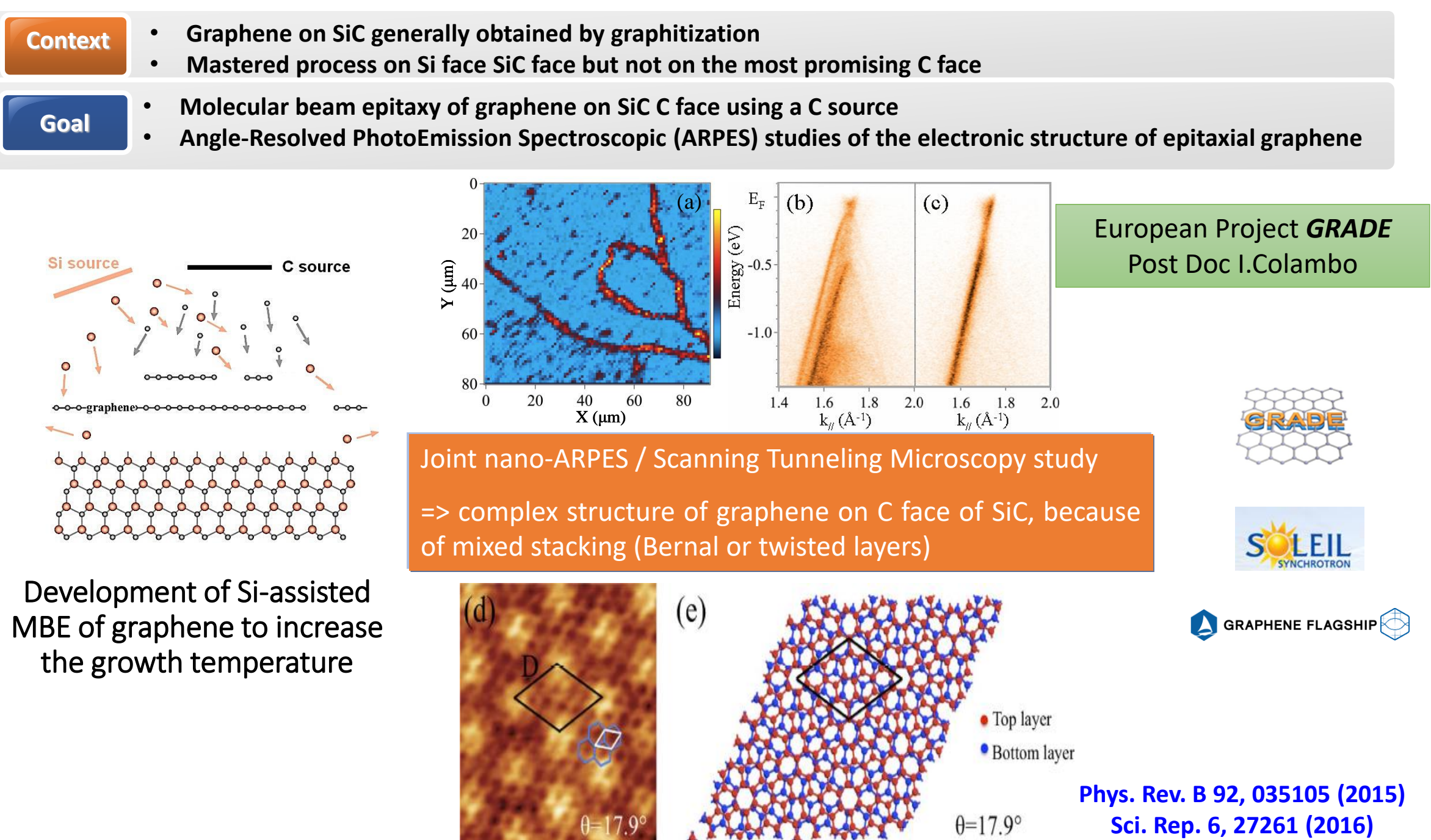
III-V based artificial graphene using top-down and bottom-up honeycomb lattice nanostructure (Coll. Physics Group, Debye Institute of Nanomaterials Science, LPCO)

#### ANR Project DIRAC35

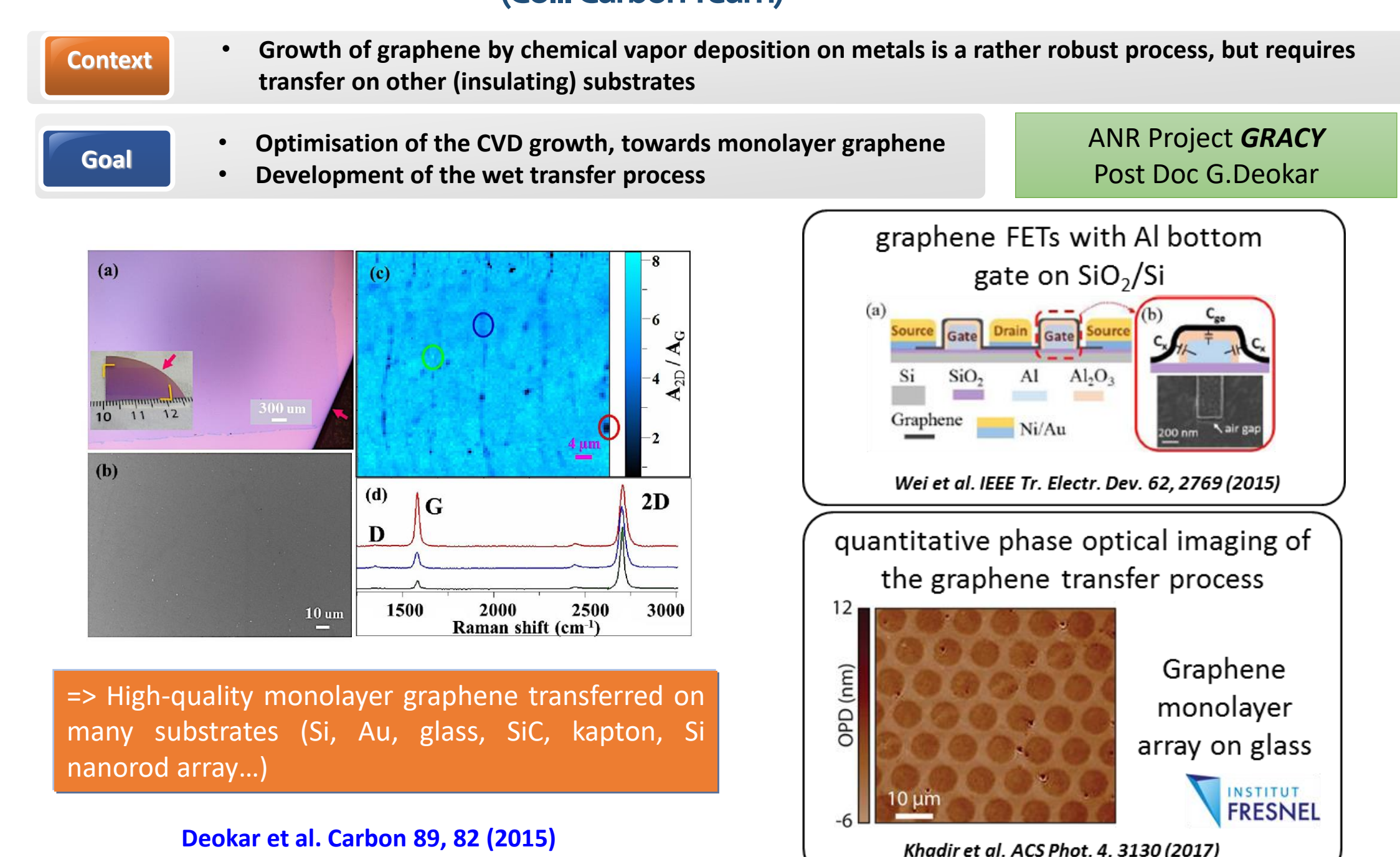


## Epitaxy of 2D materials

### MBE growth of Graphene (Coll. Synchrotron Soleil)



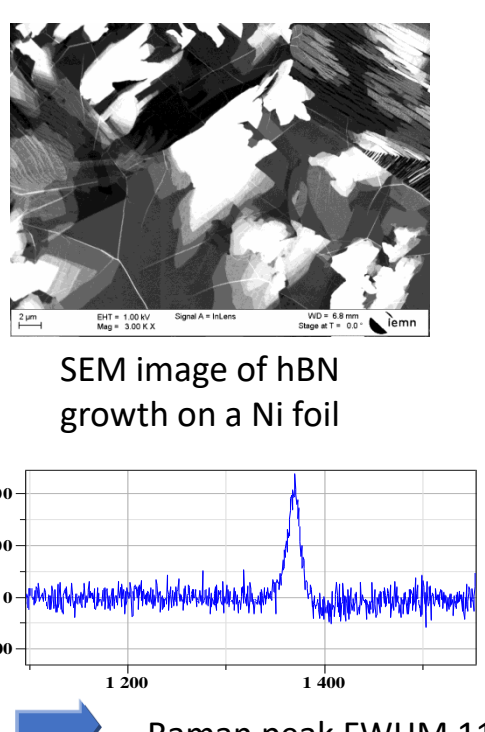
### Graphene growth by CVD on metal (Coll. Carbon Team)



### On-going studies and outlook...

Graphene/hBN heterostructures

- Goal : High quality large area hBN layer
- Molecular Beam Epitaxy
- 2 approaches
  - Atomic B effusion cell + N<sub>2</sub> RF plasma cell
  - B<sub>2</sub>N<sub>2</sub>H<sub>6</sub> gas injector + thermal cracking



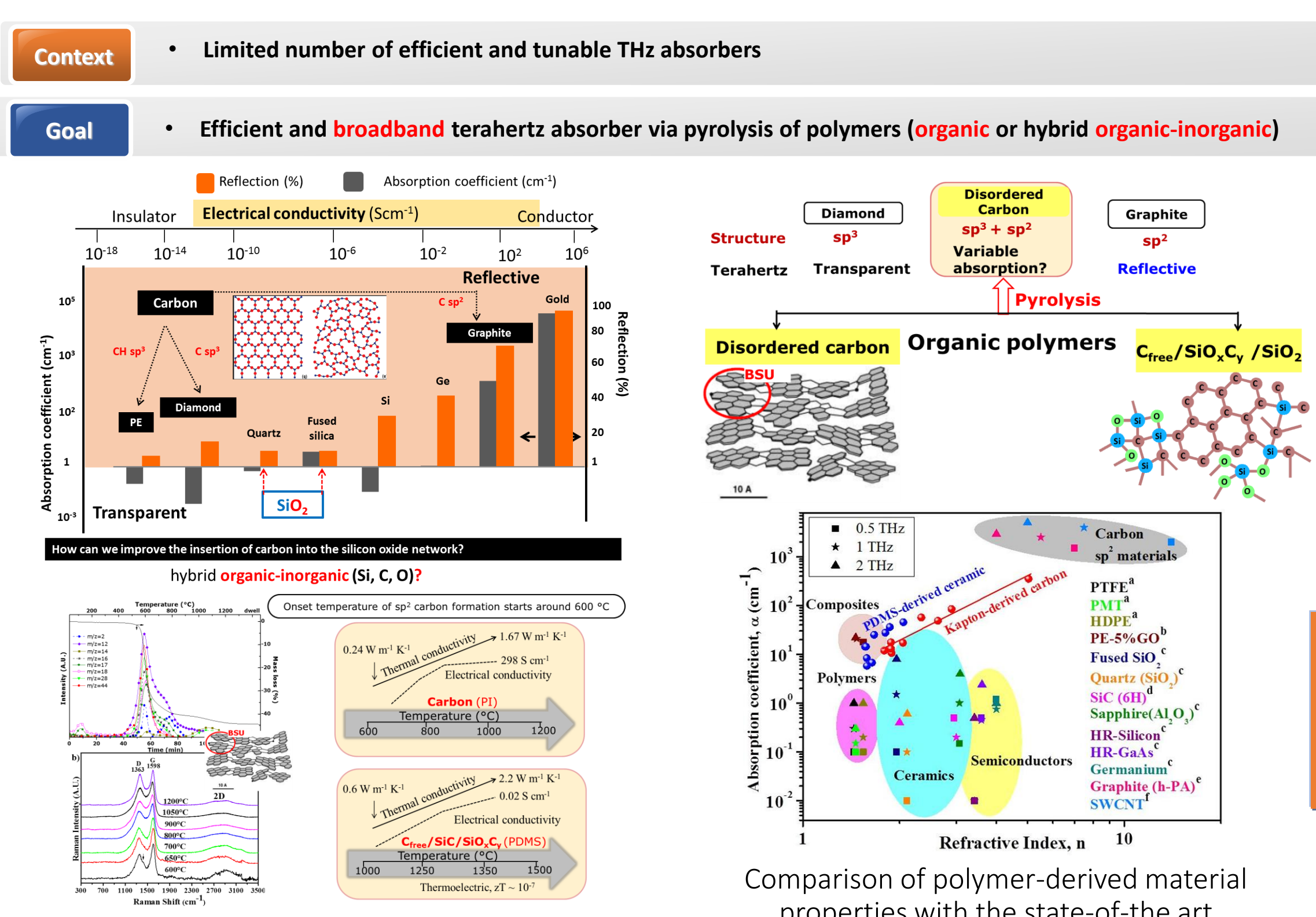
PhD thesis J. Hadid

MBE growth of Transition Metal Dichalcogenides (TMDCs)

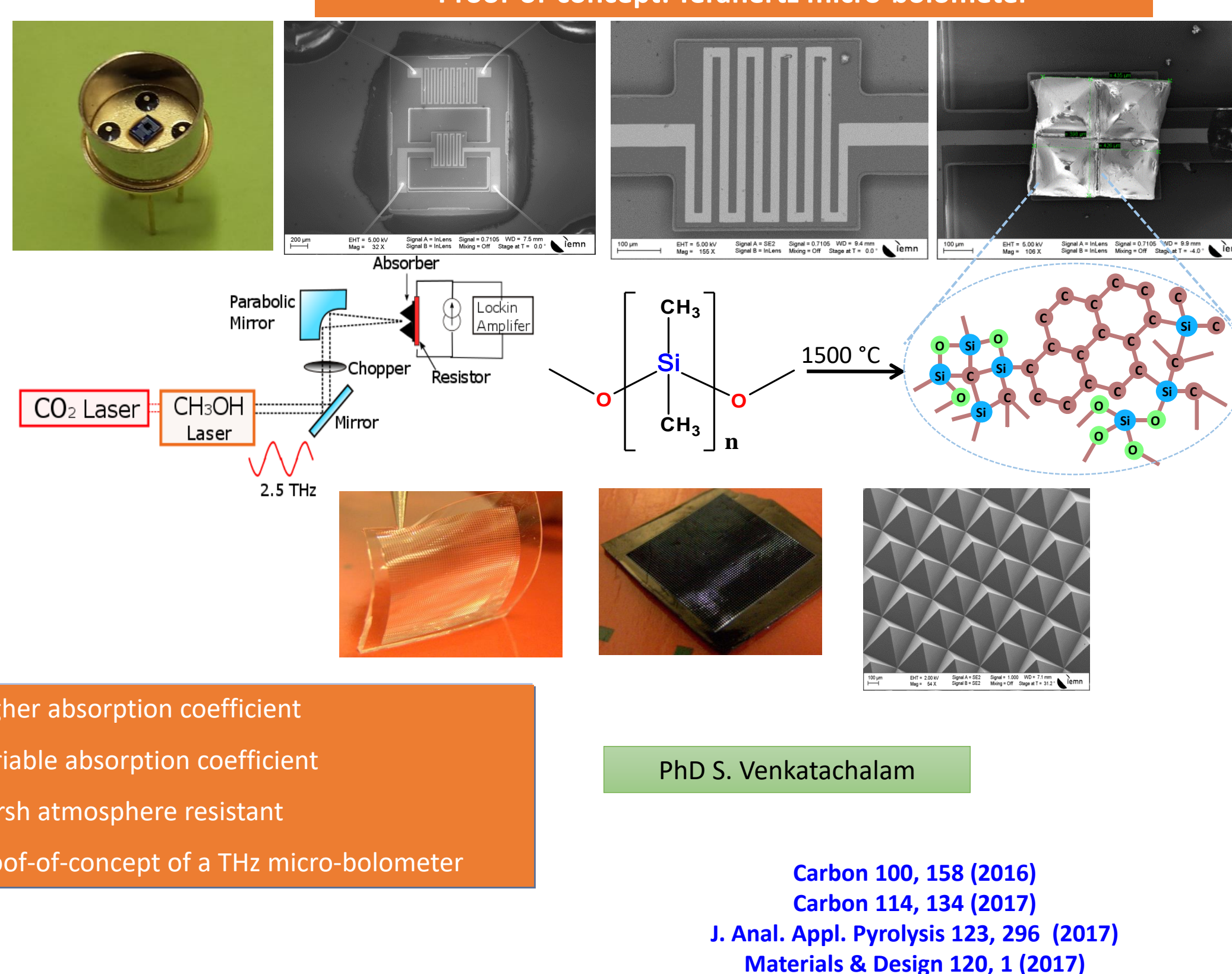
- Context : Unique properties of TMDCs
- Studies and applications mainly restricted to exfoliated materials
- Goal : large scale growth of TMDC heterostructures
- Hybrid SC/TMDC heterostructures
- New MBE reactor (scheduled installation in Fall 2019)
- UHV coupling with a III-V MBE reactor and an ESCA system

## Polymer-derived carbon materials

### Polymer-derived carbon materials for THz wave absorption (Coll. THz Photonics Group)



### Proof-of-concept: Terahertz micro-bolometer



### On-going studies and outlook...

High temperature thermoelectric materials (Coll. UDSMM)

PhD S. Shisodia

Incorporation of metal particles to increase the electrical conductivity and Seebeck coefficient of polymer derived carbon materials

Eco-friendly electromagnetic absorber: Carbon-based composites as microwave absorbers for an application in anechoic chamber (Coll. IETR)

PEPS-CNRS ARCHIVET

- Context : Commercial absorbers : carbon particles loaded polyurethane foam
- Expensive, subject to damage, < 200 MHz ??
- Better absorption performance with Carbon-Epoxy prototype
- Goal : Carbon embedded into EPOXY matrix
- Use of seaweeds as eco-friendly carbon source

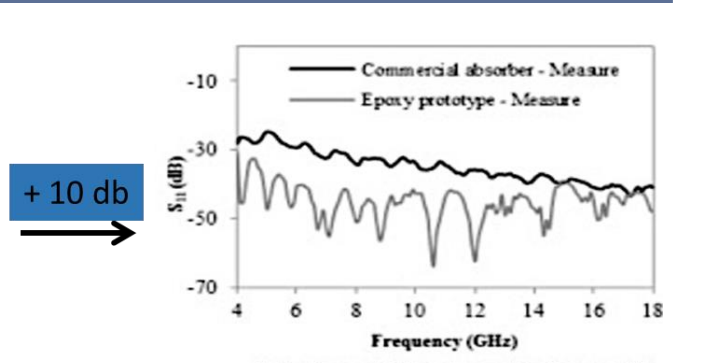


Lightweight

High performance

Cost effective

Desirable shape and size



<https://www.iemn.fr/la-recherche/les-groupes/epiphy>



<https://www.iemn.fr>